

# NTR1P02LT1

## Power MOSFET

### -20 V, -1.3 A, P-Channel SOT-23 Package

These miniature surface mount MOSFETs low  $R_{DS(on)}$  assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc-dc converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

#### Features

- Low  $R_{DS(on)}$  Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Pb-Free Package is Available

#### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DS}$	-20	V
Gate-to-Source Voltage – Continuous	$V_{GS}$	$\pm 12$	V
Drain Current	$I_D$	-1.3	A
– Continuous @ $T_A = 25^\circ\text{C}$	$I_{DM}$	-4.0	A
– Pulsed Drain Current ( $t_p \leq 10 \mu\text{s}$ )			
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$P_D$	400	mW
Operating and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150	$^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	300	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	$T_L$	260	$^\circ\text{C}$

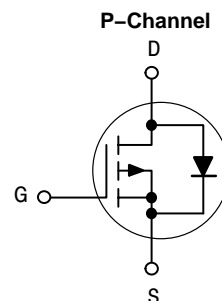
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



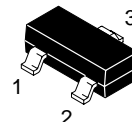
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<http://onsemi.com>

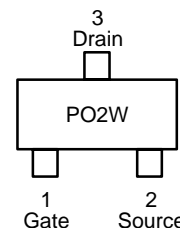
$V_{(BR)DSS}$	$R_{DS(on)} \text{ MAX}$	$I_D \text{ MAX}$
-20 V	220 m $\Omega$	-1.3 A



#### MARKING DIAGRAM/ PIN ASSIGNMENT



SOT-23  
CASE 318  
STYLE 21



PO2 = Specific Device Code  
W = Work Week

#### ORDERING INFORMATION

Device	Package	Shipping†
NTR1P02LT1	SOT-23	3000 Tape & Reel
NTR1P02LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
NTR1P02LT3	SOT-23	10,000 Tape & Reel
NTR1P02LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NTR1P02LT1

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage ( $V_{GS} = 0\text{ V}$ , $I_D = -10\text{ }\mu\text{A}$ )	$V_{(BR)DSS}$	-20			V
Zero Gate Voltage Drain Current ( $V_{DS} = -16\text{ V}$ , $V_{GS} = 0\text{ V}$ ) ( $V_{DS} = -16\text{ V}$ , $V_{GS} = 0\text{ V}$ , $T_J = 125^\circ\text{C}$ )	$I_{DSS}$			-1.0 -10	$\mu\text{A}$
Gate-Body Leakage Current ( $V_{GS} = \pm 12\text{ V}$ , $V_{DS} = 0\text{ V}$ )	$I_{GSS}$			$\pm 100$	nA

### ON CHARACTERISTICS (Note 1)

Gate Threshold Voltage ( $V_{DS} = V_{GS}$ , $I_D = -250\text{ }\mu\text{A}$ )	$V_{GS(th)}$	-0.7	-1.0	-1.25	V
Static Drain-to-Source On-Resistance ( $V_{GS} = -4.5\text{ V}$ , $I_D = -0.75\text{ A}$ ) ( $V_{GS} = -2.5\text{ V}$ , $I_D = -0.5\text{ A}$ )	$r_{DS(on)}$		0.135 0.190	0.22 0.35	$\Omega$

### DYNAMIC CHARACTERISTICS

Input Capacitance	( $V_{DS} = -5.0\text{ V}$ )	$C_{iss}$		225	pF
Output Capacitance	( $V_{DS} = -5.0\text{ V}$ )	$C_{oss}$		130	
Transfer Capacitance	( $V_{DG} = -5.0\text{ V}$ )	$C_{rss}$		55	

### SWITCHING CHARACTERISTICS (Note 2)

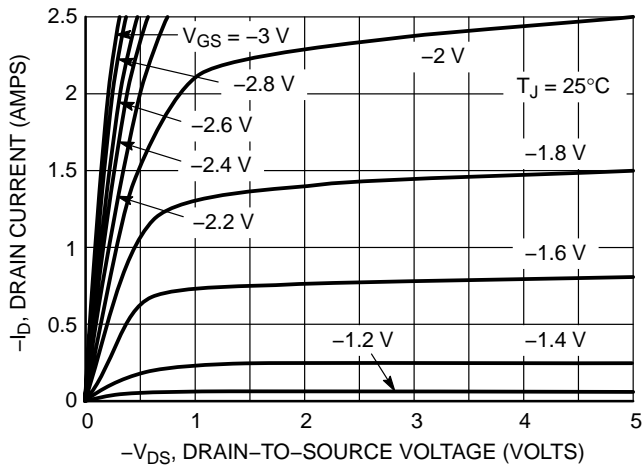
Turn-On Delay Time	(V <sub>DD</sub> = -5.0 V, I <sub>D</sub> = -1.0 A, R <sub>L</sub> = 5.0 $\Omega$ , R <sub>G</sub> = 6.0 $\Omega$ )	$t_{d(on)}$		7.0	ns
Rise Time		$t_r$		15	
Turn-Off Delay Time		$t_{d(off)}$		18	
Fall Time		$t_f$		20	
Total Gate Charge	(V <sub>DS</sub> = -16 V, I <sub>D</sub> = -1.5 A, V <sub>GS</sub> = -4.0 V)	$Q_T$		5500	pC

### SOURCE-DRAIN DIODE CHARACTERISTICS

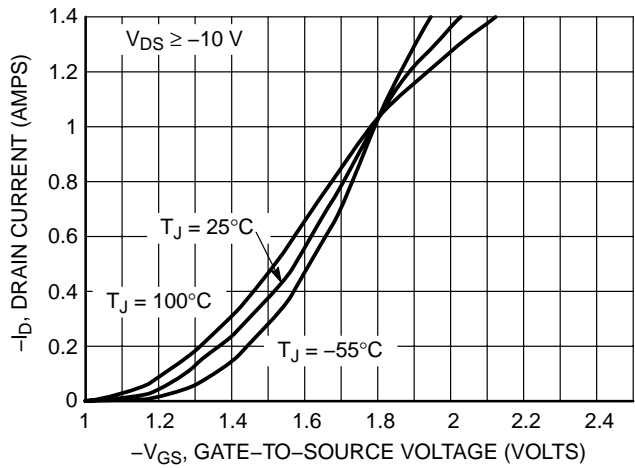
Continuous Current		$I_S$			-0.6	A
Pulsed Current		$I_{SM}$			-0.75	
Forward Voltage (Note 2) ( $V_{GS} = 0\text{ V}$ , $I_S = -0.6\text{ A}$ )		$V_{SD}$			-1.0	V
Reverse Recovery Time	(I <sub>S</sub> = -1.0 A, V <sub>GS</sub> = 0 V, dI <sub>S</sub> /dt = 100 A/ $\mu\text{s}$ )	$t_{rr}$		16		ns
		$t_a$		11		
		$t_b$		5.5		
Reverse Recovery Stored Charge		$Q_{RR}$		0.0085		$\mu\text{C}$

1. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
2. Switching characteristics are independent of operating junction temperature.

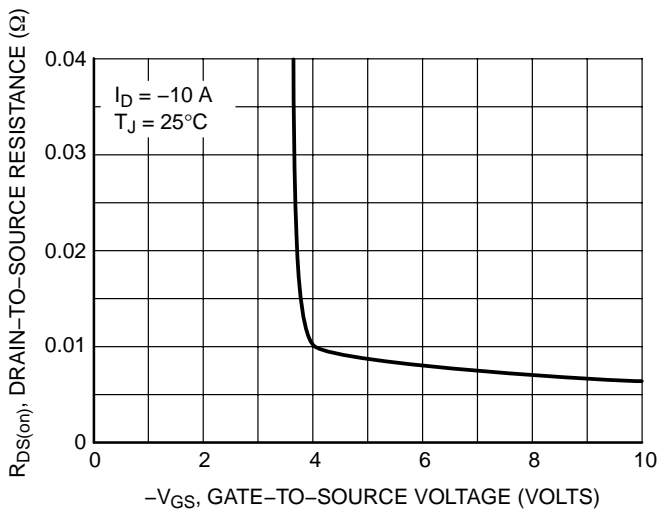
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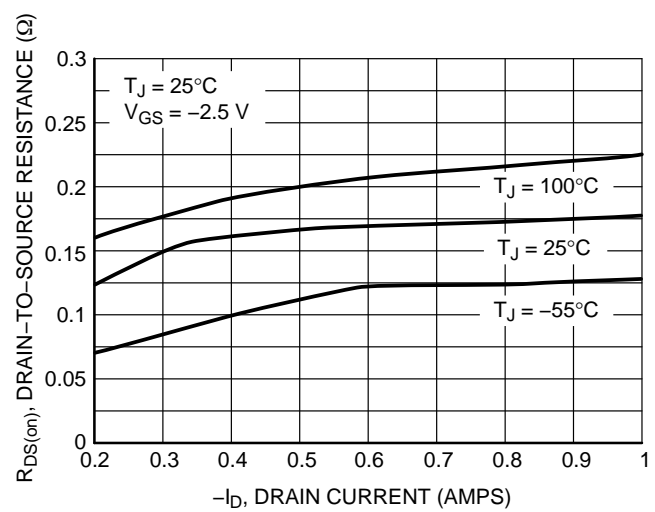
**Figure 1. On-Region Characteristics**



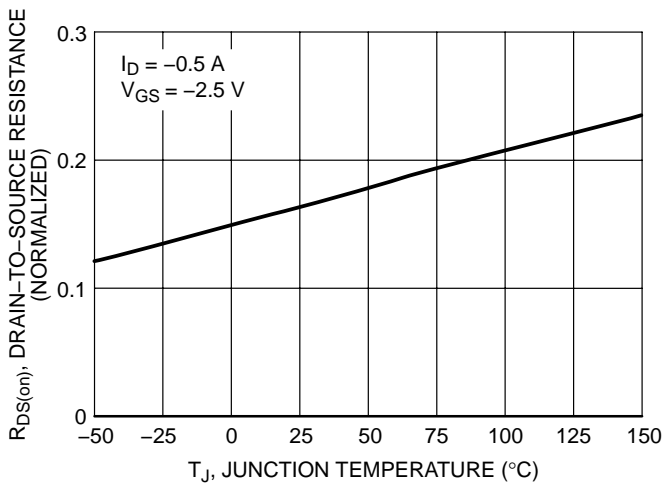
**Figure 2. Transfer Characteristics**



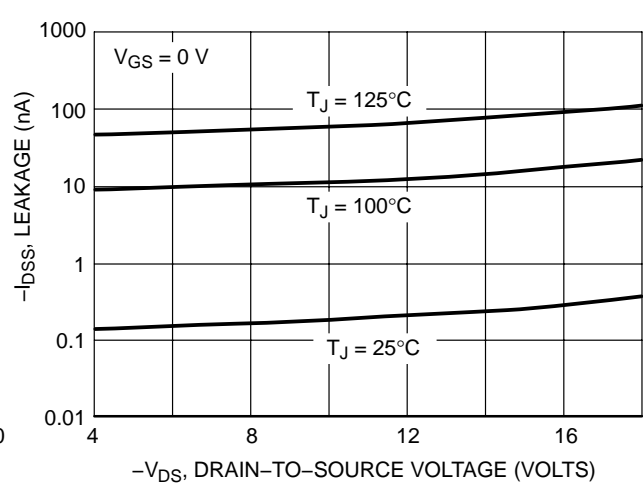
**Figure 3. On-Resistance versus Gate-to-Source Voltage**



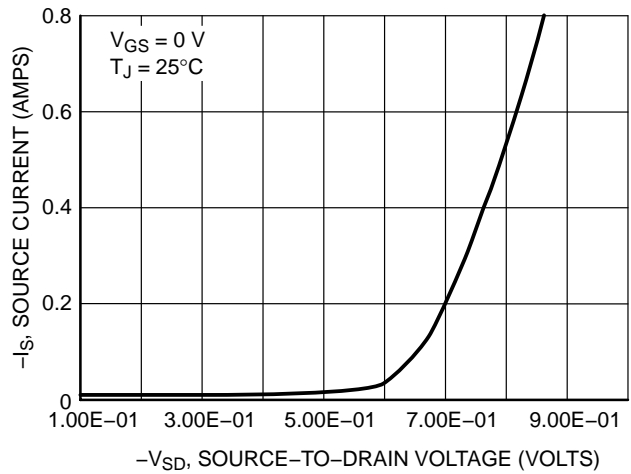
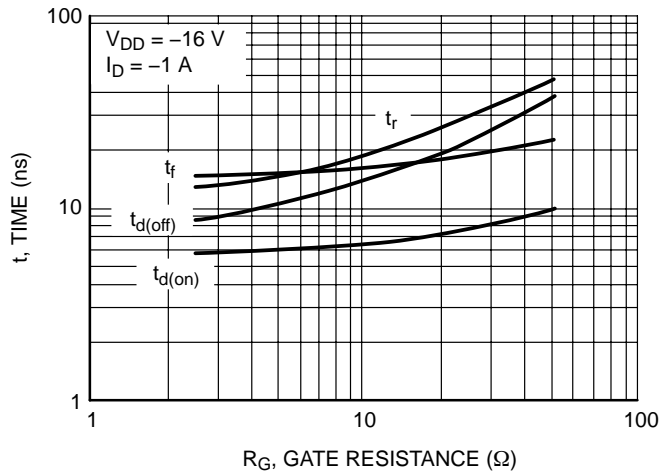
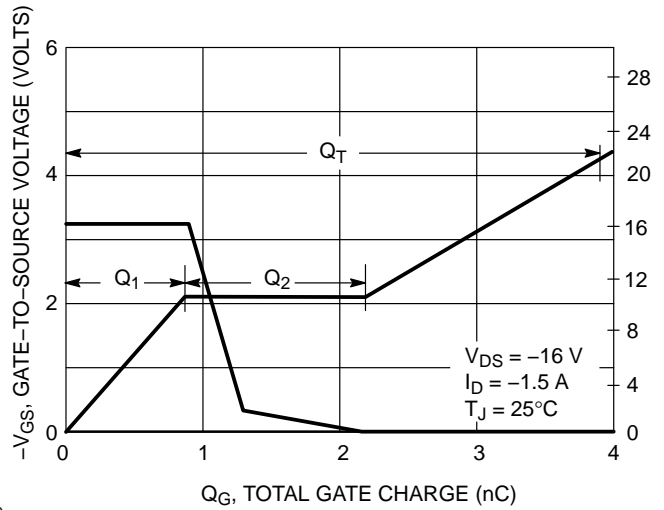
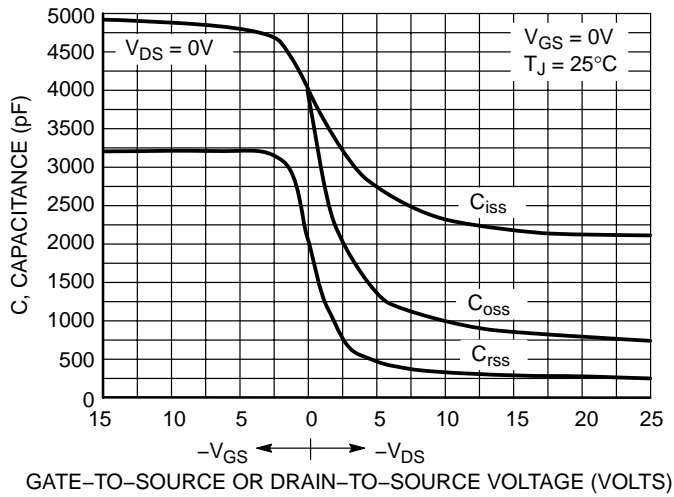
**Figure 4. On-Resistance versus Drain Current and Gate Voltage**



**Figure 5. On-Resistance Variation with Temperature**



**Figure 6. Drain-to-Source Leakage Current versus Voltage**



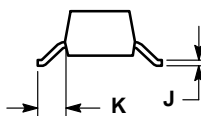
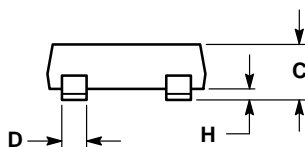
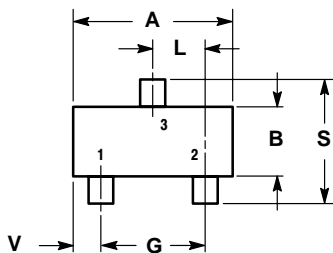
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## PACKAGE DIMENSIONS

SOT-23 (TO-236)

CASE 318-09

ISSUE AJ



### NOTES:

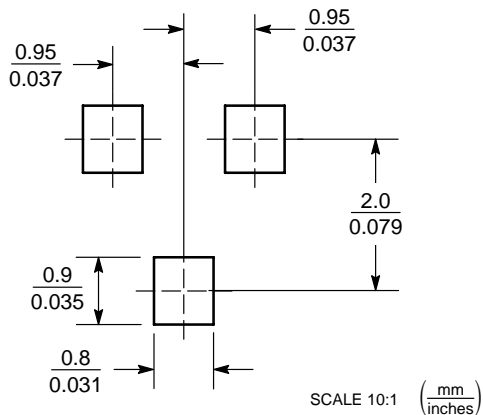
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01, -02, AND -06 OBSOLETE, NEW STANDARD 318-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0385	0.0498	0.99	1.26
D	0.0140	0.0200	0.36	0.50
G	0.0670	0.0826	1.70	2.10
H	0.0040	0.0098	0.10	0.25
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

### STYLE 21:

1. GATE
2. SOURCE
3. DRAIN

## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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